

NOTE

EVIDENCE FOR Sn-N π -BONDING:
DIPOLE MOMENTS OF AMINOSTANNANES

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The question of the existence of π -bonding in silicon–nitrogen compounds is the subject of controversy. Objections^{1,2} are still made to acceptance of this concept although evidence in favour of it has emerged from various detailed physical studies^{3,4,5} (for a review see ref. 5). The increase in reactivity when passing from aminosilanes and aminogermanes to aminostannanes⁶ indicates a weakening of the metal–nitrogen bond in this series and therefore a decrease in bond strength. Reactivity considerations, however, provide a rather uncertain guide to bond strengths, and better evidence can be derived from force constants calculated for the metal–nitrogen bond in the series M(NMe₂)₄ (where M=Si, Ge, Sn, Ti)⁷. These force constants clearly indicate bond orders for all compounds >1, provided no anomalous structures are present and assuming reasonable force constants available for the corresponding metal–nitrogen single bonds. Analogous conclusions were drawn for (dimethylamino)silanes⁸ X_{4-n}Si(NMe₂)_n (where X=H, Cl, CH₃; n=1 to 4), extrapolating from bond orders >1 to π -bonding in the metal–nitrogen bond. Additional support for π -bonding in Sn–N-compounds of the type R_{4-n}Sn(NR₂)₄ is now given by measurements of the electric dipole moments in solution. The data obtained are summarized in Table 1.

Assuming constant partial moments for the R_{4-n}Sn moiety the trends observed in the series may be rationalized in terms of three factors as follows:

TABLE 1
DIPOLE MOMENTS OF DIALKYLAMINOSTANNANES (IN DEBYE UNITS)

Compound	R=CH ₃	R=C ₂ H ₅	R=n-C ₄ H ₉	R=C ₆ H ₅
R ₃ SnNMe ₂	1.09	1.56	1.90	1.02
R ₃ SnNEt ₂	0.85	0.82	0.55	1.08
R ₂ Sn(NMe ₂) ₂	1.33	1.34	1.47	1.51
R ₂ Sn(NEt ₂) ₂	0.82	1.05	0.89	1.07
RSn(NMe ₂) ₃	1.36	1.42	1.40	1.24
RSn(NEt ₂) ₃	1.02	1.01	1.04	1.38
Sn(NMe ₂) ₄	1.15			
C(NMe ₂) ₄	0.00			

- (i) Variation of the Sn–N-bond partial moment in the range of 0.8–1.1 (D).
- (ii) Contribution of some preferred conformations of the alkyl substituents, e.g. in the butyl-tin compounds, to the total dipole moment.
- (iii) A minor contribution of the Sn–C π -bonding in the (dialkylamino)phenylstannanes as compared with the chloro(phenyl)stannanes^{9,10}.

The parent compound of amino derivatives of Group IV, tetrakis(dimethylamino)methane, C(NMe₂)₄—a detailed investigation of its IR spectrum is now being carried out in these laboratories—has no electric dipole moment in benzene solution; thus the distinct dipole moment of Sn(NMe₂)₄ is not in accord with a full T_d symmetry, although the SnN₄ site symmetry is probably tetrahedral, an assumption which was also made by Bürger and Sawodny⁷. The rather low Sn–N bond partial moments for (dialkylamino)stannanes may arise from back-bonding due to different polarity in the Sn–N σ -bonds and the Sn–N π -bonds.

We are carrying out a detailed investigation of other dialkylamides of Group IV and V elements by means of dipole moment measurements, and the results will be presented later.

EXPERIMENTAL

Preparation of compounds

The preparation and properties of aminostannanes and their identification by physical methods has been described in the literature^{6,11}; C[NMe₂]₄ was prepared according to Weingarten *et al.*¹² and purified by vacuum sublimation. All manipulations were carried out in an atmosphere of dry nitrogen or argon.

Dipole moments

Dipole moments were determined with a commercial WTW Dipolmeter Type DM 01 of Wissenschaftlich-Technische Werkstätten, Weilheim, West Germany, fitted with a 20 cc cell. Benzene was distilled from potassium and passed through molecular sieves before use.

TABLE 2
EXPERIMENTAL DATA

Compound (Mol.wt.)	ω	ϵ	a_n	a	P_0	μ
Me ₃ SnNMe ₂ (207.883)	0.010213	0.007280	0.0881	0.6247	24.43	1.09
Me ₃ SnNET ₂ (235.937)	0.007132	0.001927		0.2702	15.34	0.87
	0.010156	0.002826		0.2487	14.12	0.83
Me ₂ Sn(NMe ₂) ₂ (236.926)	0.007322	0.007298	0.2049	0.7918	35.29	1.31
	0.007302	0.007298	0.1643	0.8351	37.22	1.35
Me ₂ Sn(NEt ₂) ₂ (293.034)	0.006030	0.001841	0.04981	0.2556	14.09	0.83
	0.008132	0.002569	0.0738	0.2422	13.35	0.81
MeSn(NMe ₂) ₃ (265.969)	0.006303	0.005026	0.0476	0.7497	37.51	1.35
	0.008951	0.007123	0.0335	0.7623	38.14	1.37

TABLE 2 (continued)

Compound (Mol.wt.)	ω	ε	a_n	a	P_o	μ
MeSn(NEt ₂) ₃ (350.129)	0.006519 0.006677	0.002141 0.002098	— —	0.3285 0.3142	21.63 20.69	1.03 1.01
Et ₃ SnNMe ₂ (249.964)	0.004856 0.005783	0.004810 0.005843	0.0617 0.0518	1.0522 1.0622	49.46 49.94	1.56 1.56
Et ₃ SnNNEt ₂ (278.018)	0.012240 0.008880	0.004064 0.002535	0.0245 0.0676	0.3075 0.2179	16.08 11.39	0.89 0.75
Et ₂ Sn(NMe ₂) ₂ (264.980)	0.011958 0.006055	0.007672 0.004015	0.0752 0.0990	0.7167 0.7620	35.72 37.98	1.32 1.36
Et ₂ Sn(NEt ₂) ₂ (321.086)	0.018115 0.007252	0.006337 0.003496	— 0.0827	0.3498 0.3994	21.13 24.12	1.02 1.09
EtSn(NMe ₂) ₃ (279.996)	0.005334 0.004590	0.003498 0.003061	0.1124 0.1307	0.7680 0.7974	40.45 42.00	1.41 1.43
EtSn(NEt ₂) ₃ (364.154)	0.006333 0.007524	0.002360 0.002797	0.0474 0.0798	0.3252 0.2920	22.28 20.00	1.04 0.99
n-Bu ₃ SnNMe ₂ (334.126)	0.005497 0.004189	0.005923 0.004333	0.1091 0.1432	1.1866 1.1777	74.49 73.93	1.91 1.90
n-Bu ₃ SnNNEt ₂ (362.184)	0.008356 0.008161	0.001355 0.001311	0.0718 0.0735	0.0903 0.0871	6.15 5.94	0.55 0.54
n-Bu ₂ Sn(NMe ₂) ₂ (321.088)	0.007780 0.007077	0.006949 0.006909	0.0385 0.0424	0.7334 0.7333	44.30 44.29	1.47 1.47
n-Bu ₂ Sn(NEt ₂) ₂ (377.200)	0.007651 0.008646	0.002316 0.002578	0.0784 0.0694	0.2243 0.2288	15.91 16.23	0.88 0.89
n-BuSn(NMe ₂) ₃ (308.050)	0.009535 0.009788	0.006281 0.006519	0.0314 0.0306	0.6901 0.6966	39.98 40.36	1.40 1.40
n-BuSn(NEt ₂) ₃ (392.216)	0.006696 0.008819	0.002272 0.003278	0.0448 0.0680	0.2945 0.3036	21.73 22.40	1.03 1.04
Ph ₃ SnNMe ₂ (394.098)	0.007471 0.006447	0.004015 0.003538	0.2409 0.2792	0.2964 0.2695	21.97 19.98	1.04 0.99
Ph ₃ SnNNEt ₂ (422.148)	0.005480 0.005531	0.002447 0.002360	0.1642 0.1085	0.2823 0.1085	22.42 25.26	1.05 1.11
Ph ₂ Sn(NMe ₂) ₂ (361.068)	0.004346 0.003258	0.002464 0.001908	0.1380 0.0920	0.7051 0.6775	47.93 46.02	1.53 1.50
Ph ₂ Sn(NEt ₂) ₂ (417.176)	0.007478 0.006308	0.003321 0.002316	0.1204 0.0951	0.3238 0.2721	25.41 21.35	1.11 1.02
PhSn(NMe ₂) ₃ (328.040)	0.010819 0.008709	0.005923 0.004651	0.0277 0.0344	0.5197 0.4996	32.07 30.83	1.25 1.23
PhSn(NEt ₂) ₃ (412.204)	0.007318 0.008334	0.004545 0.005463	0.1229 0.1440	0.4980 0.5114	38.62 39.66	1.37 1.39
Sn(NMe ₂) ₄ (295.012)	0.006569 0.014555	0.002663 0.005645	0.0913 0.0824	0.4967 0.4885	26.93 27.11	1.15 1.15

Dipole moments were calculated following the procedure of Guggenheim¹³. Experimental data are listed in Table 2; ω =mole fraction; ε =dielectric constant of solution; a_n and a =slopes of concentration dependences of dielectric constants and of specific volumes; P_0 =molar polarisation of the compound studied extrapolated to infinite solution; μ =Dipole moment in Debye units. Results are obtained at 25°; standard deviations are assumed to be ± 0.05 D. No corrections for atomic polarisations have been made.

BIBLIOGRAPHY

- 1 E. W. RANDALL, J. J. ELLNER AND J. J. ZUCKERMANN, *J. Amer. Chem. Soc.*, 88 (1966) 722.
- 2 E. W. RANDALL AND J. J. ZUCKERMANN, *Chem. Commun.*, (1966) 732.
- 3 K. HEDBERG, *J. Amer. Chem. Soc.*, 77 (1955) 6491.
- 4 E. A. V. EBSWORTH, *Chem. Commun.*, (1966) 530.
- 5 E. A. V. EBSWORTH, in A. G. MACDIARMID (Ed.), *Organometallic Compounds of the Group IV Elements*, Vol. I, Part 1, Marcel Dekker, New York, 1968, p. 1-104.
- 6 K. JONES AND M. F. LAPPERT, *Organometal. Chem. Rev.*, 1 (1966) 67.
- 7 H. BÜRGER AND W. SAWODNY, *Spectrochim. Acta, Part A*, 23 (1967) 2841.
- 8 H. BÜRGER AND W. SAWODNY, *Spectrochim. Acta, Part A*, 23 (1967) 2827.
- 9 J. LORBERTH AND H. NÖTH, *Chem. Ber.*, 98 (1965) 969.
- 10 H. H. HUANG, K. M. HUI AND K. K. CHIU, *J. Organometal. Chem.*, 11 (1968) 515.
- 11 J. LORBERTH, *J. Organometal. Chem.*, 16 (1969) 235.
- 12 H. WEINGARTEN AND W. A. WHITE, *J. Amer. Chem. Soc.*, 88 (1966) 2885.
- 13 E. A. GUGGENHEIM, *Trans. Faraday Soc.*, 45 (1950) 714.

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